

Takuya Matsui

List of Publications by Year in Descending Order

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The third column is the impact factor (IF) of the journal, and the fourth column is the number of citations of the article.

82

papers

2,739

citations

27

h-index

51

g-index

95

ext. papers

3,068

ext. citations

3.5

avg, IF

4.95

L-index

| # | Paper | IF | Citations |
|----|---|-----|-----------|
| 82 | Integration of Si Heterojunction Solar Cells with III-V Solar Cells by the Pd Nanoparticle Array-Mediated "Smart Stack" Approach.. <i>ACS Applied Materials & Interfaces</i> , 2022 , | 9.5 | 3 |
| 81 | Intrinsic Amorphous Silicon Bilayers for Effective Surface Passivation in Silicon Heterojunction Solar Cells: A Comparative Study of Interfacial Layers. <i>Physica Status Solidi (A) Applications and Materials Science</i> , 2021 , 218, 2000743 | 1.6 | 9 |
| 80 | Very thin crystalline silicon cells: A way to improve the photovoltaic performance at elevated temperatures. <i>Progress in Photovoltaics: Research and Applications</i> , 2021 , 29, 1093-1104 | 6.8 | 4 |
| 79 | Nanocrystalline-silicon hole contact layers enabling efficiency improvement of silicon heterojunction solar cells: Impact of nanostructure evolution on solar cell performance. <i>Progress in Photovoltaics: Research and Applications</i> , 2021 , 29, 344-356 | 6.8 | 5 |
| 78 | Crystallite distribution analysis based on hydrogen content in thin-film nanocrystalline silicon solar cells by atom probe tomography. <i>Applied Physics Express</i> , 2021 , 14, 016501 | 2.4 | 1 |
| 77 | The sputter deposition of broadband transparent and highly conductive cerium and hydrogen co-doped indium oxide and its transfer to silicon heterojunction solar cells. <i>Progress in Photovoltaics: Research and Applications</i> , 2021 , 29, 835 | 6.8 | 5 |
| 76 | Origin of the tunable carrier selectivity of atomic-layer-deposited TiO _x nanolayers in crystalline silicon solar cells. <i>Solar Energy Materials and Solar Cells</i> , 2020 , 209, 110461 | 6.4 | 11 |
| 75 | Atomic-Layer-Deposited TiO Nanolayers Function as Efficient Hole-Selective Passivating Contacts in Silicon Solar Cells. <i>ACS Applied Materials & Interfaces</i> , 2020 , 12, 49777-49785 | 9.5 | 9 |
| 74 | Hydrogen passivation effect on p-type poly-Si/SiO _x stack for crystalline silicon solar cells 2019 , | | 2 |
| 73 | Roles of hydrogen atoms in p-type Poly-Si/SiO _x passivation layer for crystalline silicon solar cell applications. <i>Japanese Journal of Applied Physics</i> , 2019 , 58, 050915 | 1.4 | 7 |
| 72 | Potential of very thin and high-efficiency silicon heterojunction solar cells. <i>Progress in Photovoltaics: Research and Applications</i> , 2019 , 27, 1061-1070 | 6.8 | 26 |
| 71 | Thin-film microcrystalline silicon solar cells: 11.9% efficiency and beyond. <i>Applied Physics Express</i> , 2018 , 11, 022301 | 2.4 | 25 |
| 70 | Impact of carrier doping on electrical properties of laser-induced liquid-phase-crystallized silicon thin films for solar cell application. <i>Japanese Journal of Applied Physics</i> , 2018 , 57, 021302 | 1.4 | 1 |
| 69 | Honeycomb micro-textures for light trapping in multi-crystalline silicon thin-film solar cells. <i>Optics Express</i> , 2018 , 26, A498-A507 | 3.3 | 10 |
| 68 | Impact of silicon wafer thickness on photovoltaic performance of crystalline silicon heterojunction solar cells. <i>Japanese Journal of Applied Physics</i> , 2018 , 57, 08RB10 | 1.4 | 15 |
| 67 | Progress and limitations of thin-film silicon solar cells. <i>Solar Energy</i> , 2018 , 170, 486-498 | 6.8 | 23 |
| 66 | Analysis of Optical and Recombination Losses in Solar Cells. <i>Springer Series in Optical Sciences</i> , 2018 , 29-825 | | 2 |

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| 65 | Impact of intrinsic amorphous silicon bilayers in silicon heterojunction solar cells. <i>Journal of Applied Physics</i> , 2018 , 124, 103102 | 2.5 | 22 |
| 64 | Key Points in the Latest Developments of High-Efficiency Thin-Film Silicon Solar Cells. <i>Physica Status Solidi (A) Applications and Materials Science</i> , 2017 , 214, 1700544 | 1.6 | 10 |
| 63 | Investigation of atomic-layer-deposited TiO _x as selective electron and hole contacts to crystalline silicon. <i>Energy Procedia</i> , 2017 , 124, 628-634 | 2.3 | 20 |
| 62 | Role of the Fermi level in the formation of electronic band-tails and mid-gap states of hydrogenated amorphous silicon in thin-film solar cells. <i>Journal of Applied Physics</i> , 2017 , 122, 093101 | 2.5 | 3 |
| 61 | Tandem photovoltaic-photoelectrochemical GaAs/InGaAsP/WO ₃ /BiVO ₄ device for solar hydrogen generation. <i>Japanese Journal of Applied Physics</i> , 2016 , 55, 04ES01 | 1.4 | 23 |
| 60 | Stabilized 14.0%-efficient triple-junction thin-film silicon solar cell. <i>Applied Physics Letters</i> , 2016 , 109, 183506 | 3.4 | 46 |
| 59 | High-efficiency amorphous silicon solar cells: Impact of deposition rate on metastability. <i>Applied Physics Letters</i> , 2015 , 106, 053901 | 3.4 | 81 |
| 58 | High-efficiency thin-film silicon solar cells realized by integrating stable a-Si:H absorbers into improved device design. <i>Japanese Journal of Applied Physics</i> , 2015 , 54, 08KB10 | 1.4 | 43 |
| 57 | High-efficiency microcrystalline silicon solar cells on honeycomb textured substrates grown with high-rate VHF plasma-enhanced chemical vapor deposition. <i>Japanese Journal of Applied Physics</i> , 2015 , 54, 08KB05 | 1.4 | 59 |
| 56 | Analysis of bulk and interface defects in hydrogenated amorphous silicon solar cells by Fourier transform photocurrent spectroscopy. <i>Journal of Applied Physics</i> , 2015 , 118, 184506 | 2.5 | 9 |
| 55 | Triple-junction thin-film silicon solar cell fabricated on periodically textured substrate with a stabilized efficiency of 13.6%. <i>Applied Physics Letters</i> , 2015 , 106, 213902 | 3.4 | 77 |
| 54 | Photocatalytic generation of hydrogen by core-shell WO ₃ /BiVO ₄ nanorods with ultimate water splitting efficiency. <i>Scientific Reports</i> , 2015 , 5, 11141 | 4.9 | 380 |
| 53 | Effect of Front TCO Layer on Properties of Substrate-Type Thin-Film Microcrystalline Silicon Solar Cells. <i>IEEE Journal of Photovoltaics</i> , 2015 , 5, 1528-1533 | 3.7 | 8 |
| 52 | Photocurrent enhancement in thin-film silicon solar cells by combination of anti-reflective sub-wavelength structures and light-trapping textures. <i>Progress in Photovoltaics: Research and Applications</i> , 2015 , 23, 1572-1580 | 6.8 | 47 |
| 51 | Influences of deposition temperature on characteristics of B-doped ZnO films deposited by metalorganic chemical vapor deposition. <i>Thin Solid Films</i> , 2014 , 559, 83-87 | 2.2 | 21 |
| 50 | The Nature and the Kinetics of Light-Induced Defect Creation in Hydrogenated Amorphous Silicon Films and Solar Cells. <i>IEEE Journal of Photovoltaics</i> , 2014 , 4, 1331-1336 | 3.7 | 23 |
| 49 | 11.0%-Efficient Thin-Film Microcrystalline Silicon Solar Cells With Honeycomb Textured Substrates. <i>IEEE Journal of Photovoltaics</i> , 2014 , 4, 1349-1353 | 3.7 | 62 |
| 48 | Effect of oxygen doping in microcrystalline SiGe p-i-n solar cells. <i>Journal of Applied Physics</i> , 2014 , 116, 053701 | 2.5 | 11 |

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| 47 | Improved metastability and performance of amorphous silicon solar cells. <i>Materials Research Society Symposia Proceedings</i> , 2014 , 1666, 7 | | 2 |
| 46 | Advanced materials processing for high-efficiency thin-film silicon solar cells. <i>Solar Energy Materials and Solar Cells</i> , 2013 , 119, 156-162 | 6.4 | 23 |
| 45 | Microcrystalline Silicon Solar Cells with 10.5% Efficiency Realized by Improved Photon Absorption via Periodic Textures and Highly Transparent Conductive Oxide. <i>Applied Physics Express</i> , 2013 , 6, 104101 | 2.4 | 47 |
| 44 | High-efficiency thin-film silicon solar cells with improved light-soaking stability. <i>Progress in Photovoltaics: Research and Applications</i> , 2013 , 21, 1363-1369 | 6.8 | 59 |
| 43 | Enhanced infrared transmission of GZO film by rapid thermal annealing for Si thin film solar cells. <i>Progress in Photovoltaics: Research and Applications</i> , 2012 , 20, 111-116 | 6.8 | 6 |
| 42 | Amorphous-Silicon-Based Thin-Film Solar Cells Exhibiting Low Light-Induced Degradation. <i>Japanese Journal of Applied Physics</i> , 2012 , 51, 10NB04 | 1.4 | 6 |
| 41 | Compensation of Native Defect Acceptors in Microcrystalline Ge and Si _{1-x} Ge _x Thin Films by Oxygen Incorporation: Electrical Properties and Solar Cell Performance. <i>Japanese Journal of Applied Physics</i> , 2012 , 51, 091302 | 1.4 | 2 |
| 40 | Amorphous-Silicon-Based Thin-Film Solar Cells Exhibiting Low Light-Induced Degradation. <i>Japanese Journal of Applied Physics</i> , 2012 , 51, 10NB04 | 1.4 | 7 |
| 39 | Compensation of Native Defect Acceptors in Microcrystalline Ge and Si _{1-x} Ge _x Thin Films by Oxygen Incorporation: Electrical Properties and Solar Cell Performance. <i>Japanese Journal of Applied Physics</i> , 2012 , 51, 091302 | 1.4 | 2 |
| 38 | High-Efficiency Microcrystalline Silicon and Microcrystalline Silicon-Germanium Alloy Solar Cells. <i>Materials Research Society Symposia Proceedings</i> , 2011 , 1321, 21 | | 5 |
| 37 | Application of microcrystalline Si _{1-x} Ge _x infrared absorbers in triple junction solar cells 2010 , | | 4 |
| 36 | Thin Film Solar Cells Prepared on Low Thermal Budget Polycrystalline Silicon Seed Layers. <i>Japanese Journal of Applied Physics</i> , 2010 , 49, 112301 | 1.4 | 12 |
| 35 | Potential of thin-film silicon solar cells by using high haze TCO superstrates. <i>Thin Solid Films</i> , 2010 , 518, 3054-3058 | 2.2 | 66 |
| 34 | Thin film solar cells incorporating microcrystalline Si _{1-x} Ge _x as efficient infrared absorber: an application to double junction tandem solar cells. <i>Progress in Photovoltaics: Research and Applications</i> , 2010 , 18, 48-53 | 6.8 | 40 |
| 33 | Highly-transparent ZnO:Ga through rapid thermal annealing for low-bandgap solar cell application 2009 , | | 3 |
| 32 | Photovoltaic Action in Polyaniline/n-GaN Schottky Diodes. <i>Applied Physics Express</i> , 2009 , 2, 092201 | 2.4 | 17 |
| 31 | Thin film solar cells based on microcrystalline silicon-germanium narrow-gap absorbers. <i>Solar Energy Materials and Solar Cells</i> , 2009 , 93, 1100-1102 | 6.4 | 31 |
| 30 | Microcrystalline Si _{1-x} Ge _x Solar Cells Exhibiting Enhanced Infrared Response with Reduced Absorber Thickness. <i>Applied Physics Express</i> , 2008 , 1, 031501 | 2.4 | 27 |

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| 29 | Microcrystalline silicon-germanium thin films prepared by the chemical transport process using hydrogen radicals. <i>Journal of Non-Crystalline Solids</i> , 2008 , 354, 2109-2112 | 3.9 | 10 |
| 28 | Electron spin resonance study of hydrogenated microcrystalline silicon-germanium alloy thin films. <i>Journal of Non-Crystalline Solids</i> , 2008 , 354, 2365-2368 | 3.9 | 22 |
| 27 | Carrier collection characteristics of microcrystalline silicon-germanium p-i-n junction solar cells. <i>Journal of Non-Crystalline Solids</i> , 2008 , 354, 2468-2471 | 3.9 | 15 |
| 26 | Infrared analysis of the bulk silicon-hydrogen bonds as an optimization tool for high-rate deposition of microcrystalline silicon solar cells. <i>Applied Physics Letters</i> , 2008 , 92, 033506 | 3.4 | 62 |
| 25 | Formation of Low-Defect-Concentration Polycrystalline Silicon Films by Thermal Plasma Jet Crystallization Technique. <i>Japanese Journal of Applied Physics</i> , 2008 , 47, 6949-6952 | 1.4 | 15 |
| 24 | High-rate deposition of microcrystalline silicon p-i-n solar cells in the high pressure depletion regime. <i>Journal of Applied Physics</i> , 2008 , 104, 034508 | 2.5 | 91 |
| 23 | Defect Reduction in Polycrystalline Silicon Thin Films by Heat Treatment with High-Pressure H ₂ O Vapor. <i>Japanese Journal of Applied Physics</i> , 2007 , 46, 1286-1289 | 1.4 | 18 |
| 22 | Effect of illumination-induced space charge on photocarrier transport in hydrogenated microcrystalline Si _{1-x} Ge _x p-i-n solar cells. <i>Applied Physics Letters</i> , 2007 , 91, 102111 | 3.4 | 20 |
| 21 | Key issues for fabrication of high quality amorphous and microcrystalline silicon solar cells. <i>Thin Solid Films</i> , 2006 , 501, 243-246 | 2.2 | 38 |
| 20 | Highly stabilized hydrogenated amorphous silicon solar cells fabricated by triode-plasma CVD. <i>Thin Solid Films</i> , 2006 , 502, 306-310 | 2.2 | 29 |
| 19 | Measuring the Electronic Properties of Poly-Si Thin Film Solar Cells Deposited on Textured Substrate 2006 , | | 1 |
| 18 | Influence of alloy composition on carrier transport and solar cell properties of hydrogenated microcrystalline silicon-germanium thin films. <i>Applied Physics Letters</i> , 2006 , 89, 142115 | 3.4 | 59 |
| 17 | Improvement in quantum efficiency of thin film Si solar cells due to the suppression of optical reflectance at transparent conducting oxide/Si interface by TiO ₂ /SnO ₂ antireflection coating. <i>Applied Physics Letters</i> , 2006 , 88, 183508 | 3.4 | 72 |
| 16 | Carrier Transport in Microcrystalline Silicon-Germanium Alloy Films and Solar Cells 2006 , | | 1 |
| 15 | Microcrystalline silicon-germanium alloys for solar cell application: Growth and material properties. <i>Journal of Non-Crystalline Solids</i> , 2006 , 352, 1255-1258 | 3.9 | 34 |
| 14 | High-rate microcrystalline silicon deposition for p-i-n junction solar cells. <i>Solar Energy Materials and Solar Cells</i> , 2006 , 90, 3199-3204 | 6.4 | 56 |
| 13 | Improved Stability of Hydrogenated Amorphous Silicon Solar Cells Fabricated by Triode-Plasma CVD. <i>Materials Research Society Symposia Proceedings</i> , 2005 , 862, 1111 | | 1 |
| 12 | High-Rate Plasma Process for Microcrystalline Silicon: Over 9% Efficiency Single Junction Solar Cells. <i>Materials Research Society Symposia Proceedings</i> , 2004 , 808, 395 | | 6 |

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| 11 | Doping properties of boron-doped microcrystalline silicon from B ₂ H ₆ and BF ₃ : material properties and solar cell performance. <i>Journal of Non-Crystalline Solids</i> , 2004 , 338-340, 646-650 | 3.9 | 17 |
| 10 | Carrier Transport in Polycrystalline Silicon Photovoltaic Layer on Highly Textured Substrate. <i>Japanese Journal of Applied Physics</i> , 2003 , 42, 6753-6758 | 1.4 | 10 |
| 9 | Correlation between Microstructure and Electronic Property of Solar-Grade Poly-Si Thin-Films Deposited on Textured Substrates. <i>Solid State Phenomena</i> , 2003 , 93, 115-120 | 0.4 | 3 |
| 8 | Origin of the Improved Performance of High-Deposition-Rate Microcrystalline Silicon Solar Cells by High-Pressure Glow Discharge. <i>Japanese Journal of Applied Physics</i> , 2003 , 42, L901-L903 | 1.4 | 70 |
| 7 | Correlation between Microstructure and Photovoltaic Performance of Polycrystalline Silicon Thin Film Solar Cells. <i>Japanese Journal of Applied Physics</i> , 2002 , 41, 20-27 | 1.4 | 64 |
| 6 | Microstructural dependence of electron and hole transport in low-temperature-grown polycrystalline-silicon thin-film solar cells. <i>Applied Physics Letters</i> , 2002 , 81, 4751-4753 | 3.4 | 28 |
| 5 | Influence of substrate texture on microstructure and photovoltaic performances of thin film polycrystalline silicon solar cells. <i>Journal of Non-Crystalline Solids</i> , 2002 , 299-302, 1152-1156 | 3.9 | 47 |
| 4 | 2D-numerical analysis and optimum design of thin film silicon solar cells. <i>Solar Energy Materials and Solar Cells</i> , 2001 , 65, 87-93 | 6.4 | 12 |
| 3 | Theoretical analysis of the effect of conduction band offset of window/CIS layers on performance of CIS solar cells using device simulation. <i>Solar Energy Materials and Solar Cells</i> , 2001 , 67, 83-88 | 6.4 | 468 |
| 2 | Crucial processing steps for microcrystalline silicon bottom cells | | 2 |
| 1 | Very Thin (56 μ m) Silicon Heterojunction Solar Cells with an Efficiency of 23.3% and an Open-Circuit Voltage of 754 mV. <i>Solar Rrl</i> , 2100634 | 7.1 | 4 |